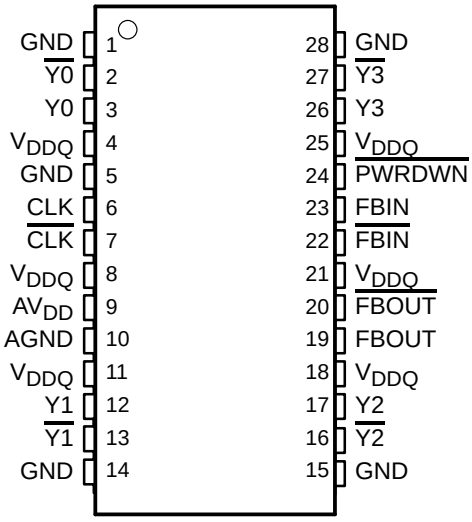
- **Phase-Lock Loop Clock Driver for Double Data-Rate Synchronous DRAM Applications**
- **Spread Spectrum Clock Compatible**
- **Operating Frequency: 60 MHz to 180 MHz**
- **Low Jitter (cyc–cyc): ±50 ps**
- **Distributes One Differential Clock Input to Four Differential Clock Outputs**
- **Enters Low Power Mode and Three-State Outputs When Input CLK Signal Is Less Than 20 MHz or PWRDWN Is Low**
- **Operates From Dual 2.5-V Supplies**
- **28-Pin TSSOP Package**
- **Consumes < 200-μA Quiescent Current**
- **External Feedback PIN (FBIN, $\overline{\text{FBIN}}$) Are Used to Synchronize the Outputs to the Input Clocks**

PW PACKAGE
(TOP VIEW)



description

The CDCV855 is a high-performance, low-skew, low-jitter zero delay buffer that distributes a differential clock input pair (CLK, $\overline{\text{CLK}}$) to four differential pairs of clock outputs (Y[0:3], $\overline{\text{Y[0:3]}}$) and one differential pair of feedback clock outputs (FBOUT, $\overline{\text{FBOUT}}$). When $\overline{\text{PWRDWN}}$ is high, the outputs switch in phase and frequency with CLK. When $\overline{\text{PWRDWN}}$ is low, all outputs are disabled to a high-impedance state (3-state), and the PLL is shut down (low-power mode). The device also enters this low-power mode when the input frequency falls below a suggested detection frequency that is below 20 MHz (typical 10 MHz). An input frequency detection circuit detects the low-frequency condition and after applying a >20-MHz input signal this detection circuit turns on the PLL again and enables the outputs.

When AV_{DD} is tied to GND, the PLL is turned off and bypassed for test purposes. The CDCV855 is also able to track spread spectrum clocking for reduced EMI.

Since the CDCV855 is based on PLL circuitry, it requires a stabilization time to achieve phase-lock of the PLL. This stabilization time is required following power up. The CDCV855 is characterized for both commercial and industrial temperature ranges.

AVAILABLE OPTIONS

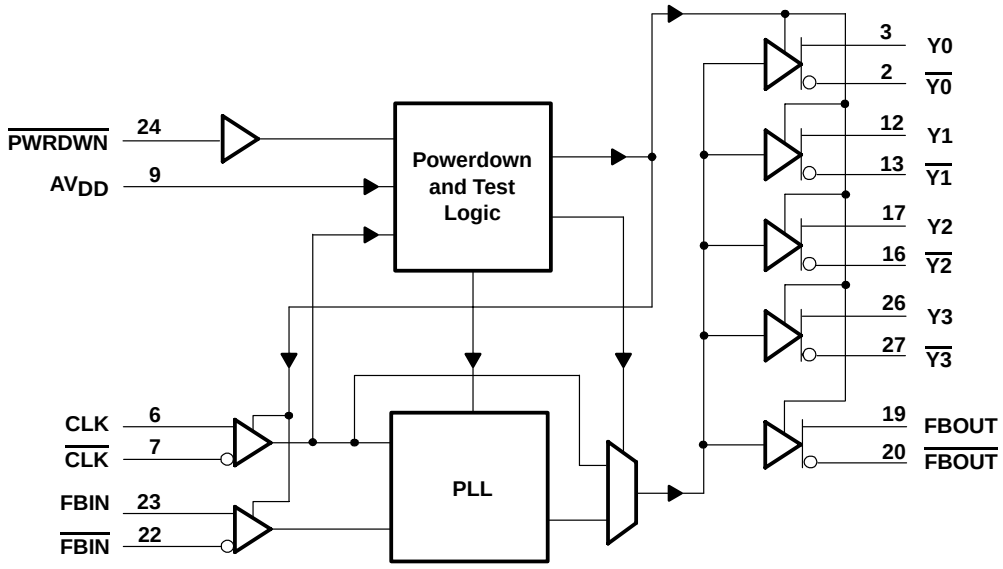
T_A	PACKAGED DEVICES
	TSSOP (PW)
0°C to 70°C	CDCV855PW
–40°C to 85°C	CDCV855IPW

FUNCTION TABLE
(Select Functions)

INPUTS				OUTPUTS				PLL
AV_{DD}	$\overline{PWRDWN}$	CLK	$\overline{CLK}$	Y[0:3]	$\overline{Y[0:3]}$	FBOUT	$\overline{FBOUT}$	
GND	H	L	H	L	H	L	H	Bypassed/Off
GND	H	H	L	H	L	H	L	Bypassed/Off
X	L	L	H	Z	Z	Z	Z	Off
X	L	H	L	Z	Z	Z	Z	Off
2.5 V (nom)	H	L	H	L	H	L	H	On
2.5 V (nom)	H	H	L	H	L	H	L	On
2.5 V (nom)	X	<20 MHz†	<20 MHz†	Z	Z	Z	Z	Off

† Typically 10 MHz

functional block diagram



Terminal Functions

TERMINAL NAME	TERMINAL NO.	I/O	DESCRIPTION
AGND	10		Ground for 2.5-V analog supply
AV_{DD}	9		2.5-V analog supply
CLK, $\overline{CLK}$	6, 7	I	Differential clock input
FBIN, $\overline{FBIN}$	23, 22	I	Feedback differential clock input
FBOUT, $\overline{FBOUT}$	19, 20	O	Feedback differential clock output
GND	1, 5, 14, 15, 28		Ground
$\overline{PWRDWN}$	24	I	Control input to turn device in the power-down mode
V_{DDQ}	4, 8, 11, 18, 21, 25		2.5-V supply
Y[0:3]	3, 12, 17, 26	O	Buffered output copies of input clock, CLK
$\overline{Y[0:3]}$	2, 13, 16, 27	O	Buffered output copies of input clock, $\overline{CLK}$

absolute maximum ratings over operating free-air temperature (unless otherwise noted)†

Supply voltage range, V_{DDQ}, AV_{DD} . . . . . –0.5 V to 3.6 V
Input voltage range, V_I (see Notes 1 and 2) . . . . . –0.5 V to V_{DDQ} + 0.5 V
Output voltage range, V_O (see Notes 1 and 2) . . . . . –0.5 V to V_{DDQ} + 0.5 V
Input clamp current, I_{IK} (V_I < 0 or V_I > V_{DDQ}) . . . . . ±50 mA
Output clamp current, I_{OK} (V_O < 0 or V_O > V_{DDQ}) . . . . . ±50 mA
Continuous output current, I_O (V_O = 0 to V_{DDQ}) . . . . . ±50 mA
Continuous current to GND or V_{DDQ} . . . . . ±100 mA
Package thermal impedance, θ_{JA} (see Note 3): PW package . . . . . 105.8°C/W
Storage temperature range T_{stg} . . . . . –65°C to 150°C

† Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output negative voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
2. This value is limited to 3.6 V maximum.
3. The package thermal impedance is calculated in accordance with JESD 51.

recommended operating conditions (see Note 4)

		MIN	TYP	MAX	UNIT
Supply voltage, V_{DDQ}, AV_{DD}		2.3		2.7	V
Low-level input voltage, V_{IL}	CLK, $\overline{CLK}$, FBIN, $\overline{FBIN}$			$V_{DDQ}/2 - 0.18$	V
	$\overline{PWRDWN}$	–0.3		0.7	
High-level input voltage, V_{IH}	CLK, $\overline{CLK}$, FBIN, $\overline{FBIN}$	$V_{DDQ}/2 + 0.18$			V
	$\overline{PWRDWN}$	1.7		V_{DDQ} + 0.3	
DC input signal voltage (see Note 5)		–0.3		V_{DDQ}	V
Differential input signal voltage, V_{ID} (see Note 6)	CLK, FBIN	0.36		V_{DDQ} + 0.6	V
Output differential cross-voltage, $V_{O(X)}$ (see Note 7)		$V_{DDQ}/2 - 0.2$	$V_{DDQ}/2$	$V_{DDQ}/2 + 0.2$	V
Input differential pair cross-voltage, $V_{I(X)}$ (see Note 7)		$V_{DDQ}/2 - 0.2$		$V_{DDQ}/2 + 0.2$	V
High-level output current, I_{OH}				–12	mA
Low-level output current, I_{OL}				12	mA
Input slew rate, SR (see Figure 7)		1		4	V/ns
Operating free-air temperature, T_A	Commercial	0		85	°C
	Industrial	–40		85	

NOTES: 4. Unused inputs must be held high or low to prevent them from floating.
5. DC input signal voltage specifies the allowable dc execution of differential input.
6. Differential input signal voltage specifies the differential voltage |VTR – VCP| required for switching, where VTR is the true input level and VCP is the complementary input level.
7. Differential cross-point voltage is expected to track variations of V_{DDQ} and is the voltage at which the differential signals must be crossing.

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER			TEST CONDITIONS		MIN	TYP†	MAX	UNIT
V_{IK}	Input voltage	All inputs	V_{DDQ} = 2.3 V,	I_I = –18 mA			–1.2	V
V_{OH}	High-level output voltage		V_{DDQ} = min to max,	I_{OH} = –1 mA	V_{DDQ} – 0.1			V
			V_{DDQ} = 2.3 V,	I_{OH} = –12 mA	1.7			
V_{OL}	Low-level output voltage		V_{DDQ} = min to max,	I_{OL} = 1 mA			0.1	V
			V_{DDQ} = 2.3 V,	I_{OL} = 12 mA			0.6	
I_{OH}	High-level output current		V_{DDQ} = 2.3 V,	V_O = 1 V	–18	–32		mA
I_{OL}	Low-level output current		V_{DDQ} = 2.3 V,	V_O = 1.2 V	26	35		mA
V_{OD}	Output voltage swing		Differential outputs are terminated with 120 Ω		1.1		V_{DDQ} – 0.4	V
V_{OX}	Output differential cross-voltage‡				$V_{DDQ}/2$ – 0.2	$V_{DDQ}/2$	$V_{DDQ}/2$ + 0.2	
I_I	Input current		V_{DDQ} = 2.7 V,	V_I = 0 V to 2.7 V			±10	µA
I_{OZ}	High-impedance-state output current		V_{DDQ} = 2.7 V,	V_O = V_{DDQ} or GND			±10	µA
$I_{DD(PD)}$	Power-down current on V_{DDQ} + AV_{DD}		CLK and $\overline{CLK}$ = 0 MHz; $\overline{PWRDWN}$ = Low; Σ of I_{DD} and AI_{DD}			100	200	µA
I_{DD}	Dynamic current on V_{DDQ}		Differential outputs are terminated with 120 Ω / CL = 14 pF	f_O = 167 MHz		150	180	mA
			Differential outputs are terminated with 120 Ω / CL = 0 pF			130	160	
AI_{DD}	Supply current on AV_{DD}		f_O = 167 MHz			8	10	mA
C_I	Input capacitance		V_{DDQ} = 2.5 V	V_I = V_{DDQ} or GND	2	2.5	3	pF
C_O	Output capacitance		V_{DDQ} = 2.5 V	V_O = V_{DDQ} or GND	2.5	3	3.5	pF

† All typical values are at respective nominal V_{DDQ}.
‡ Differential cross-point voltage is expected to track variation of V_{DDQ} and is the voltage at which the differential signals must be crossing.

timing requirements over recommended ranges of supply voltage and operating free-air temperature

PARAMETER		MIN	MAX	UNIT
f_{CLK}	Operating clock frequency	60	180	MHz
	Input clock duty cycle	40%	60%	
	Stabilization time (PLL mode)¶		10	µs
	Stabilization time (Bypass mode)§		30	ns

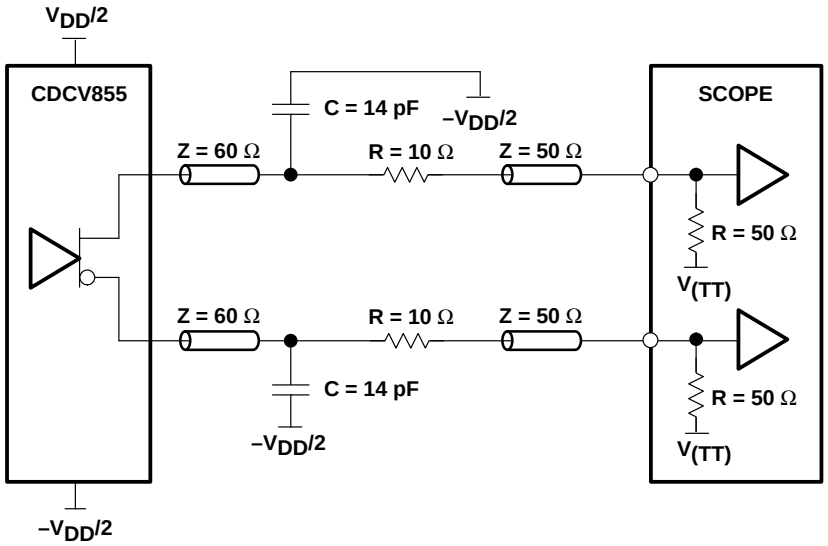
§ Recovery time required when the device goes from power-down mode into bypass mode (test mode with AV_{DD} at GND).
¶ Time required for the integrated PLL circuit to obtain phase lock of its feedback signal to its reference signal. For phase lock to be obtained, a fixed-frequency, fixed-phase reference signal must be present at CLK. Until phase lock is obtained, the specifications for propagation delay, skew, and jitter parameters given in the switching characteristics table are not applicable. This parameter does not apply for input modulation under SSC application.

switching characteristics

PARAMETER		TEST CONDITIONS		MIN	TYP†	MAX	UNIT
t_{PLH}‡	Low-to-high level propagation delay time	Test mode/CLK to any output			4.5		ns
t_{PHL}‡	High-to-low level propagation delay time	Test mode/CLK to any output			4.5		ns
$t_{jit(per)}$§	Jitter (period), See Figure 5	66 MHz		–55		55	ps
		100/133/167/180 MHz		–35		35	ps
$t_{jit(cc)}$§	Jitter (cycle-to-cycle), See Figure 2	66 MHz		–60		60	ps
		100/133/167/180 MHz		–50		50	
$t_{jit(hper)}$§	Half-period jitter, See Figure 6	66 MHz		–130		130	ps
		100 MHz		–90		90	
		133/167/180 MHz		–75		75	
$t_{slr(o)}$	Output clock slew rate, See Figure 7	Load = 120Ω / 14 pF		1		2	V/ns
		Load = 120Ω / 4 pF		1		3	V/ns
$t_{d(Ø)}$§	Dynamic phase offset (this includes jitter), See Figure 3(b)	SSC off	66 MHz	–180		180	ps
			100/133 MHz	–130		130	
			167/180 MHz	–90		90	
		SSC on	66 MHz	–230		230	
			100/133 MHz	–170		170	
			167/180 MHz	–100		100	
$t_{(Ø)}$	Static phase offset, See Figure 3(a)	66 MHz		–150		150	ps
		100/133/167/180 MHz		–100		100	
$tsk_{(o)}$¶	Output skew, See Figure 4					50	ps
tr, tf	Output rise and fall times (20% – 80%)	Load: 120 Ω/14 pF		650		900	ps

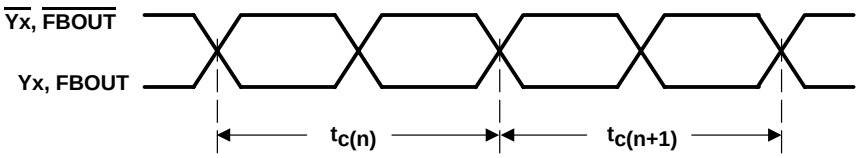
† All typical values are at a respective nominal V_{DDQ}.
‡ Refers to transition of noninverting output
§ This parameter is assured by design but can not be 100% production tested.
¶ All differential output pins are terminated with 120 Ω/14 pF.

PARAMETER MEASUREMENT INFORMATION



NOTE: $V_{(TT)}$ = GND

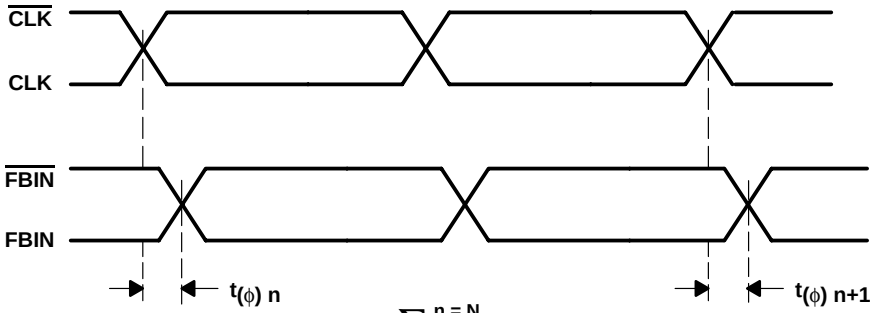
Figure 1. Output Load Test Circuit



$$t_{jit(cc)} = t_{c(n)} - t_{c(n+1)}$$

Figure 2. Cycle-to-Cycle Jitter

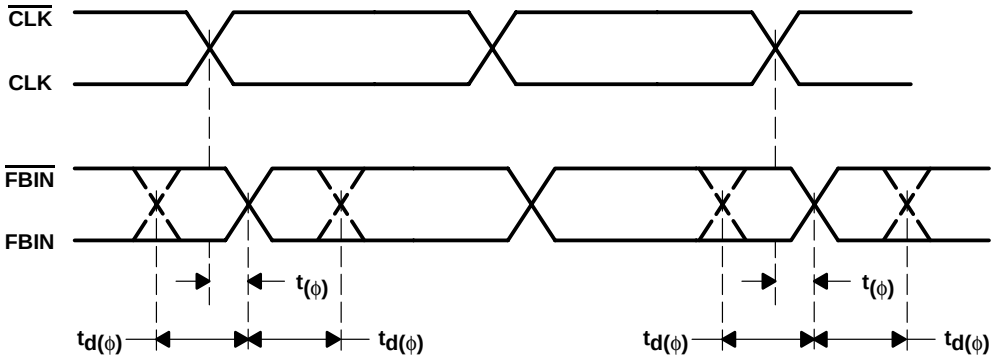
PARAMETER MEASUREMENT INFORMATION



$$t_{(\phi)} = \frac{\sum_{1}^{n=N} t_{(\phi)\,n}}{N}$$

(N is a Large Number of Samples)

(a) Static Phase Offset



(b) Dynamic Phase Offset

Figure 3. Phase Offset

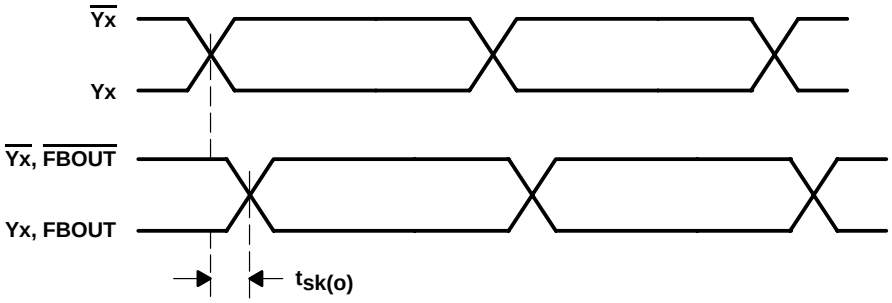


Figure 4. Output Skew

PARAMETER MEASUREMENT INFORMATION

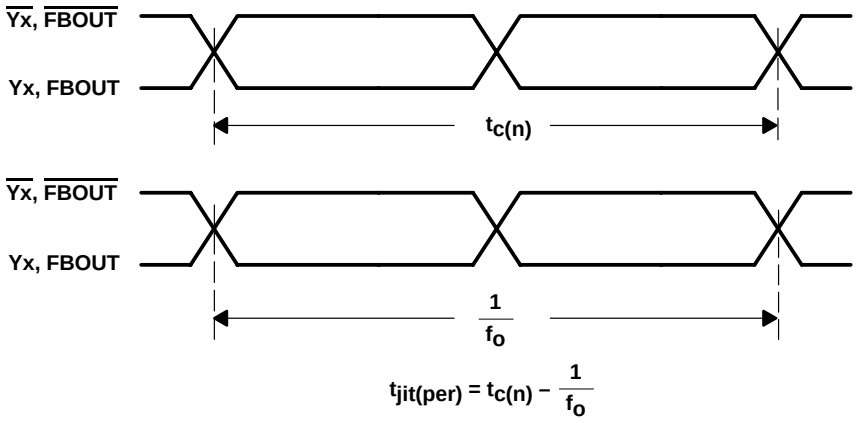


Figure 5. Period Jitter

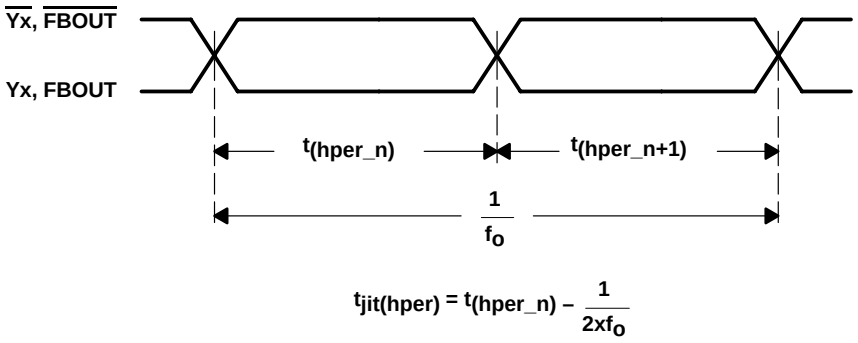


Figure 6. Half-Period Jitter

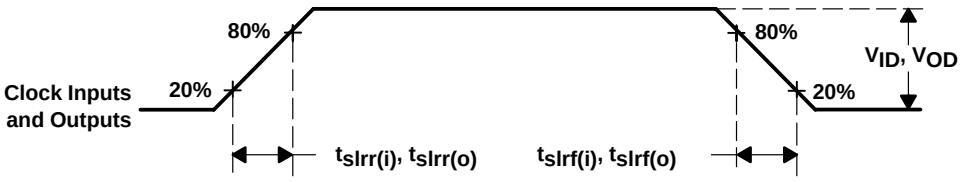


Figure 7. Input and Output Slew Rates

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
CDCV855IPW	NRND	TSSOP	PW	28	50	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CDCV855-I	
CDCV855IPWR	NRND	TSSOP	PW	28	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CDCV855-I	
CDCV855PW	NRND	TSSOP	PW	28	50	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	CDCV855	
CDCV855PWR	NRND	TSSOP	PW	28	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	CDCV855	

(1) The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".
RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.
Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

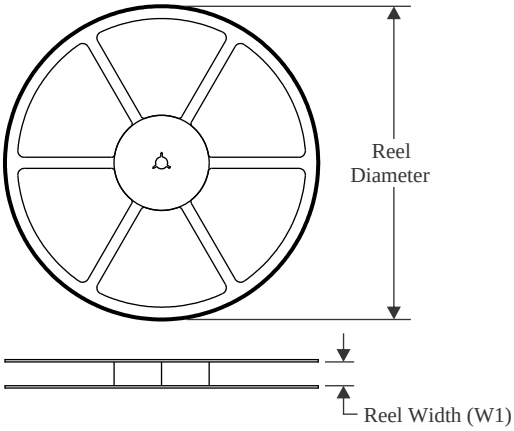
(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

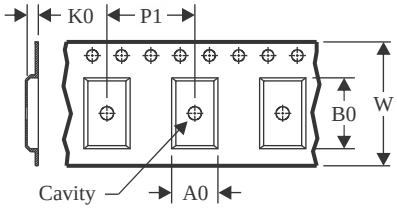
In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

TAPE AND REEL INFORMATION

REEL DIMENSIONS

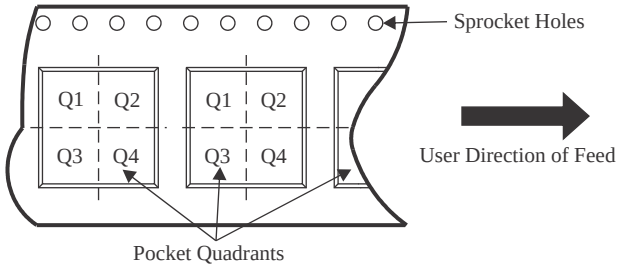


TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

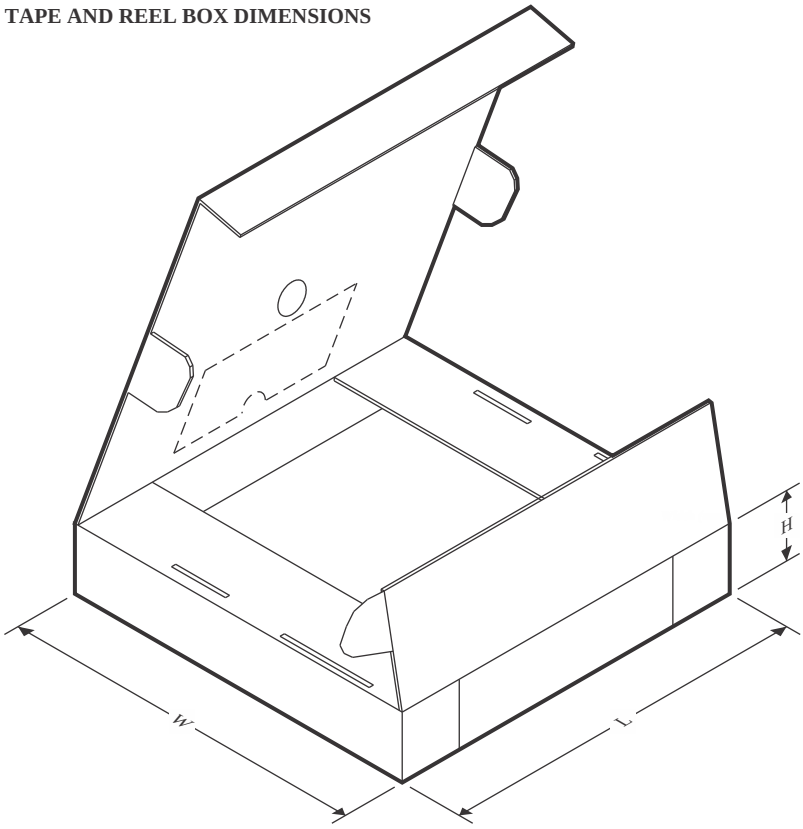
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CDCV855IPWR	TSSOP	PW	28	2000	330.0	16.4	6.9	10.2	1.8	12.0	16.0	Q1
CDCV855PWR	TSSOP	PW	28	2000	330.0	16.4	6.9	10.2	1.8	12.0	16.0	Q1

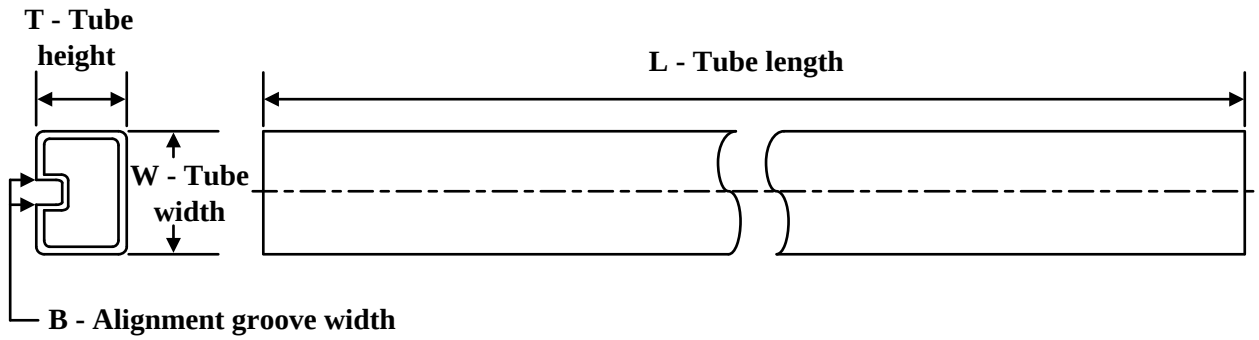
TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CDCV855IPWR	TSSOP	PW	28	2000	356.0	356.0	35.0
CDCV855PWR	TSSOP	PW	28	2000	356.0	356.0	35.0

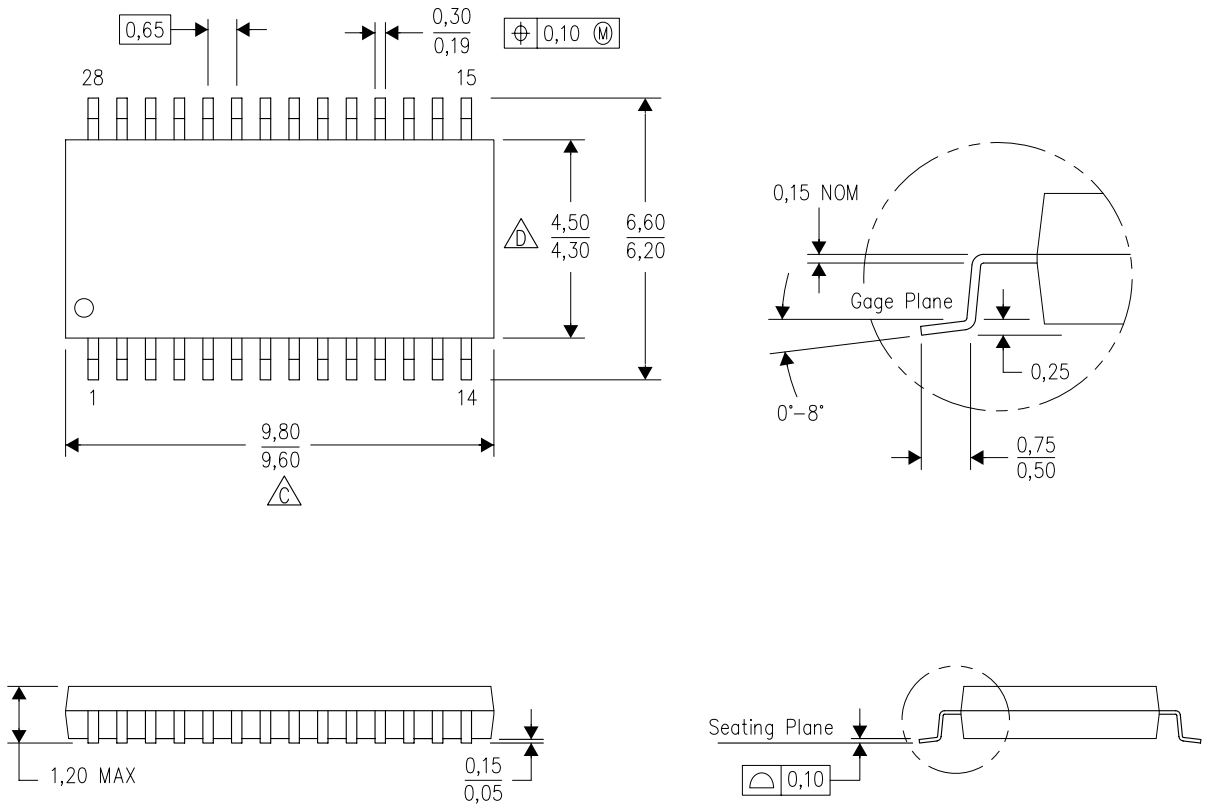
TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
CDCV855IPW	PW	TSSOP	28	50	530	10.2	3600	3.5
CDCV855PW	PW	TSSOP	28	50	530	10.2	3600	3.5

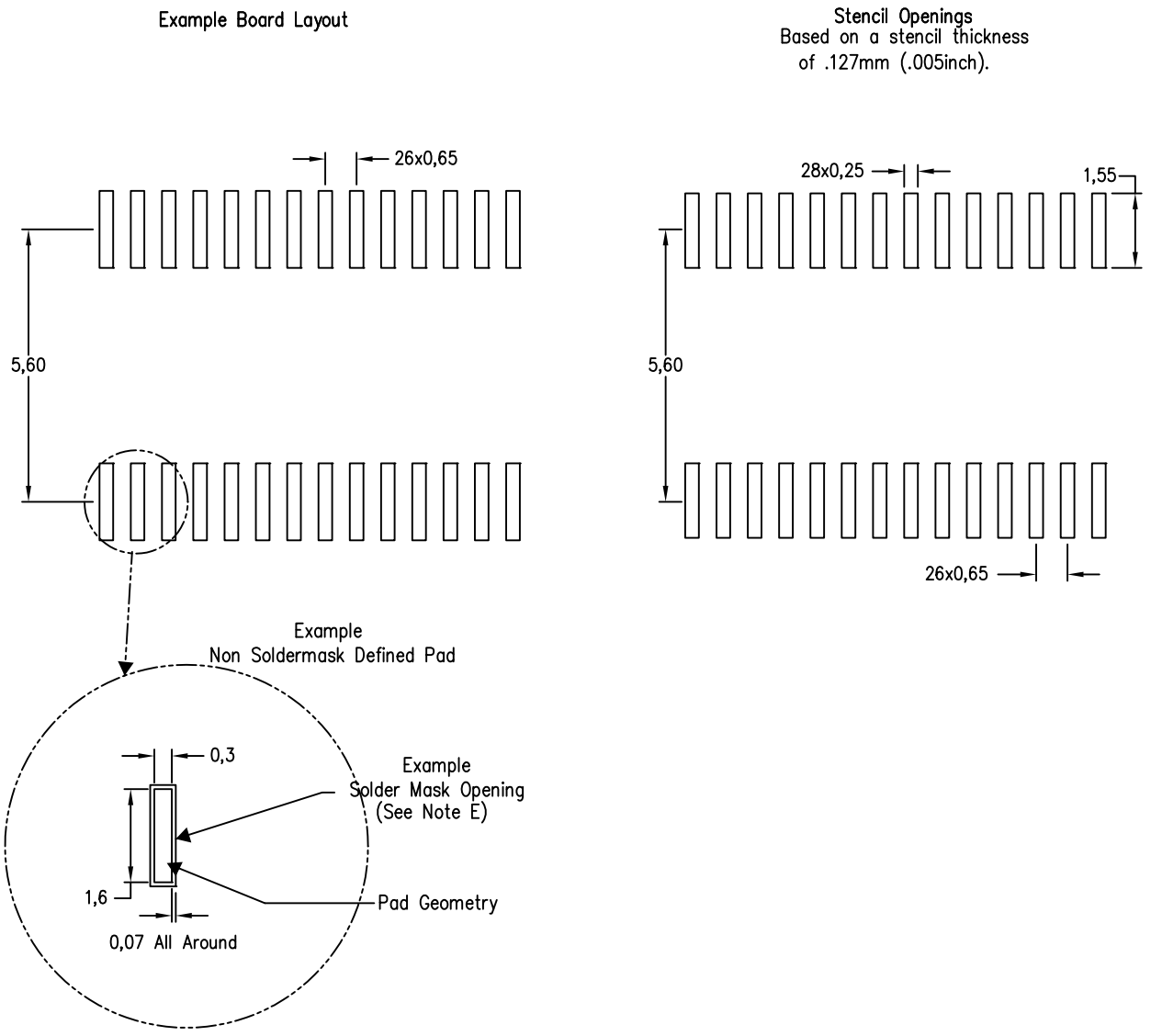
PW (R–PDSO–G28) PLASTIC SMALL OUTLINE



4040064–7/G 02/11

NOTES:
A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M–1994.
B. This drawing is subject to change without notice.
C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
D. Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
E. Falls within JEDEC MO–153

PW (R–PDSO–G28) PLASTIC SMALL OUTLINE



NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Publication IPC–7351 is recommended for alternate design.
D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC–7525 for other stencil recommendations.
E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATA SHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES “AS IS” AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI’s products are provided subject to TI’s Terms of Sale or other applicable terms available either on ti.com or provided in conjunction with such TI products. TI’s provision of these resources does not expand or otherwise alter TI’s applicable warranties or warranty disclaimers for TI products.

TI objects to and rejects any additional or different terms you may have proposed.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265